

MPFF450R17MBF 1700V450A IGBT Module

Electrical Features

- Trench/Fieldstop IGBT
- Low VCE(sat)
- VCE(sat) with positive temperature coefficient
- $10 \ \mu \ s$ short circuit capability
- Fast&soft reverse recovery anti-parallel FWD
- Low inductance case



Typical Applications

- Motor Drives
- High Power Converters
- UPS System
- Servo Drives
- Wind Turbines

IGBT, Inverter

Maximu	m Rated Values						
Symbol	Item	Conditions		Rating		Unit	
IGBT	·	÷					
V _{CES}	Collector-emitter voltage	T _{vj} =25°C	T _{vj} =25°C			1700	
V _{GES}	Gate-emitter voltage	-			±20		V
Ic	Collector current,DC	T _C =100°C,T _{vj} =175°	°C		450		A
ICRM	Repetitive peak collector current	t _p =1ms			900		A
t _{SC}	Short circuit withstand time	V _{GE} =15V, V _{CC} =800	0V, T _{vj} ≤150°C		1	0	μs
P _{tot}	Total power dissipation	T _C =25°C,T _{vj} =175°C	C		2500		W
Charact	eristics Values						
Symbol	Item	Conditions			Values		Unit
IGBT				Min.	Тур.	Max.	
ICES	Collector-emitter cut-off current	V _{CE} =1700V,V _{GE} =0V,T _{vj} =25°C		-	-	3	mA
I _{GES}	Gate leakage current	V _{CE} =0V,V _{GE} =20V,T _{vj} =25°C		-	-	400	nA
V _{GE(th)}	Gate-emitter threshold voltage	$I_C=12mA, V_{CE}=V_{GE}, T_{vj}=25^{\circ}C$		5.0	6.0	7.0	
	Collector-emitter saturation voltage	I _C =450A V _{GE} =15V	T _{vj} =25°C	-	2.4	-	v
V _{CEsat}			T _{vj} =125°C	-	-	-	
			T _{vj} =150°C	-	-	-]
Cies	Input capacitance	V -25VV -0V		-	43.8	-	
Coes	Output capacitance	$V_{CE}=25V, V_{GE}=0V$ f=1MHz, T _{vj} =25°C			1.47		nF
Cres	Reverse transfer capacitance			-	1.32	-	
Q _G	Gate charge	V _{GE} =-15V+15V		-	5.1	-	μC
Rg	Internal gate resistance	T _{vj} =25°C			1.7		Ω

			T	_	406	_	
t _{d(on)}	Turn-on delay time		$T_{vj}=25^{\circ}C$ $T_{vj}=125^{\circ}C$	-	400	-	-
u(on)	Tum-on delay time		$T_{vj}=123$ C $T_{vj}=150$ °C	-	-	-	-
		-	$T_{vj}=150$ C $T_{vj}=25$ °C	_	216	_	-
t _r	Rise time		$T_{vj}=25$ °C	-	-	_	-
ιr			$T_{vj}=120$ °C	-	_	_	-
		– V _{CC} =900V,	$T_{vj}=150$ C $T_{vj}=25$ °C	-	579	_	ns
$t_{d(off)}$	Turn-off delay time	$V_{\rm CC} = 900 V,$ I _C = 450A,	$T_{vj}=25$ °C	-	-	-	-
		$V_{GE} = \pm 15V,$	$T_{vj}=123$ C $T_{vj}=150$ °C	-	-	-	-
		$-\frac{V_{GE}-15V}{R_{G(on)}=2.4\Omega},$	$T_{vj}=150$ C $T_{vj}=25$ °C	-	361	_	-
t _f	Fall time	$R_{G(off)} = 2.4 \Omega,$	$T_{vj} = 125^{\circ}C$	-	-	_	_
ι _İ		Inductive load	$T_{vj}=120$ °C				
			$T_{vj}=150$ C $T_{vj}=25$ °C	-	- 159.7	-	
Eon	Turn-on energy (per pulse)		$T_{vj}=23^{\circ}C$ $T_{vj}=125^{\circ}C$	-	-		-
Lon	rum-on energy (per pulse)		$T_{vj}=120$ °C		-	-	-
		-	$\frac{T_{vj}=130 \text{ C}}{T_{vj}=25^{\circ}\text{C}}$	-	94.0	-	mJ
Б	Turn-off energy (per pulse)						-
E _{off}			$T_{vj}=125^{\circ}C$	-	-	-	-
D			T _{vj} =150°C	-	-	-	V/W
R _{thJC}	Thermal resistance, junction to case	per IGBT	- 1W//(V)	-	-	0.06	K/W K/W
R_{thCH}	Thermalresistance, case to heatsink	per IGBT/ λgreas	e=1 w/(m·K)	-	0.029	-	K/W
T_{vjop}	Temperature under switching conditions			-40		150	°C
Diode,							
	m Rated Values						
Symbol							
V _{RRM}		C	onditions		Rat	ina	Unit
	Item Repetitive peak reverse voltage		onditions			ting	Unit V
	Repetitive peak reverse voltage	T _{vj} =25°C	onditions		17	00	V
I _F	Repetitive peak reverse voltage Forward current,DC	T _{vj} =25°C	onditions		17 4:	00 50	V A
I _{FRM}	Repetitive peak reverse voltageForward current,DCRepetitive peak forward current		onditions		17 4:	00	V
I _{FRM}	Repetitive peak reverse voltage Forward current,DC	T _{vj} =25°C			17 4: 90	00 50 00	V A
I _{FRM} Charact	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values	T _{vj} =25°C	T _{vj} =25°C	-	17 4:	00 50	V A A
I _{FRM}	Repetitive peak reverse voltageForward current,DCRepetitive peak forward current	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$	T _{vj} =25°C T _{vj} =125°C	-	17 4: 90	00 50 00 - -	V A
I _{FRM} Charact	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$	T _{vj} =25°C T _{vj} =125°C T _{vj} =150°C	-	17 4! 90 2.23 - -	00 50 00 - - -	V A A
I _{FRM} Charact V _F	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$	Tvj=25°C Tvj=125°C Tvj=150°C Tvj=25°C		17 4: 90	00 50 00 - - - - -	V A A V
I _{FRM} Charact	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$	$ \begin{array}{c c} T_{vj} = 25^{\circ}C \\ T_{vj} = 125^{\circ}C \\ T_{vj} = 150^{\circ}C \\ T_{vj} = 25^{\circ}C \\ T_{vj} = 125^{\circ}C \\ \end{array} $	- - -	17 4! 90 2.23 - -	00 50 00 - - -	V A A
I _{FRM} Charact V _F	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$	$\begin{array}{c} T_{vj}=25^{\circ}C\\ T_{vj}=125^{\circ}C\\ T_{vj}=150^{\circ}C\\ T_{vj}=25^{\circ}C\\ T_{vj}=125^{\circ}C\\ T_{vj}=125^{\circ}C\\ T_{vj}=150^{\circ}C\\ \end{array}$	- - - -	17 4: 90 2.23 - 191.5 - -	00 50 00 - - - - - - - - -	V A A V
I _{FRM} Charact V _F I _{RM}	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline \end{array}$	- - - - -	17 4: 90 2.23 - 191.5 - 677	00 50 00 - - - - - - - - - - - - -	V A A V A
I _{FRM} Charact V _F	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$	$\begin{array}{c} T_{vj}=25^{\circ}C\\ T_{vj}=125^{\circ}C\\ T_{vj}=150^{\circ}C\\ T_{vj}=25^{\circ}C\\ T_{vj}=125^{\circ}C\\ T_{vj}=150^{\circ}C\\ T_{vj}=25^{\circ}C\\ T_{vj}=125^{\circ}C\\ T_{vj}=125^{\circ}C\\ \end{array}$	- - - - - - -	17 4: 90 2.23 - 191.5 - -	00 50 00 - - - - - - - - -	V A A V
I _{FRM} Charact V _F I _{RM}	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$ $V_{GE}=0V$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline \end{array}$	- - - - - - - -	17 4: 90 2.23 - 191.5 - 677 - -	00 50 00 - - - - - - - - - - - - -	V A A V A
I _{FRM} Charact V _F I _{RM} t _{rr}	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$ $V_{GE}=0V$ $V_{R}=900V$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ \end{array}$	- - - - - - -	17 4: 90 2.23 - 191.5 - 677 - 52	00 50 00 - - - - - - - - - - - - -	V A A V A ns
I _{FRM} Charact V _F I _{RM}	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$ $V_{GE}=0V$ $V_{R}=900V$ $I_{F}=450A$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline $	- - - - - - - - - - - -	17 4: 90 2.23 - 191.5 - 677 - -	00 50 00 - - - - - - - - - - - - - - - -	V A A V A
I _{FRM} Charact V _F I _{RM} t _{rr}	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$ $V_{GE}=0V$ $V_{R}=900V$ $I_{F}=450A$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=150^{\circ}C \\ \end{array}$	- - - - - - - - - - - - -	17 4: 90 2.23 - 191.5 - 677 - 52 - - 52 -		V A A V A ns
I _{FRM} Charact V _F I _{RM} t _{rr} Q _r	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time Recovered charge	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$ $V_{GE}=0V$ $V_{R}=900V$ $I_{F}=450A$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=125^{\circ}C \\ \hline T_{vj}=150^{\circ}C \\ \hline T_{vj}=25^{\circ}C \\ \hline \end{array}$	- - - - - - - - - - - -	17 4: 90 2.23 - 191.5 - 677 - 52		V A A V A ns µC
I _{FRM} Charact V _F I _{RM} t _{rr}	Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time	$T_{vj}=25^{\circ}C$ $t_{p}=1ms$ $I_{F}=450A$ $V_{GE}=0V$ $V_{R}=900V$ $I_{F}=450A$	$\begin{array}{c c} T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=25^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=125^{\circ}C \\ T_{vj}=150^{\circ}C \\ T_{vj}=150^{\circ}C \\ \end{array}$	- - - - - - - - - - - - -	17 4: 90 2.23 - 191.5 - 677 - 52 - - 52 -		V A A V A ns

R _{thJC}	Thermal resistance, junction to case	per diode	-	-	0.1	K/W
R _{thCH}	Thermalresistance, case to heatsink	per diode/ λ grease=1W/(m·K)	-	0.05	-	K/W
T _{vjop}	Temperature under switching conditions		-40		150	°C

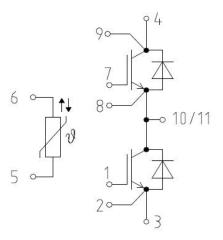
NTC Thermistor Characteristics

Symbol	Item	Conditions	Values			Unit
		Conditions	Min.	Тур.	Max.	
R ₂₅	Rated resistance	$T_{\rm C}=25^{\circ}{\rm C}$	-	5	-	kΩ
$\Delta R/R$	Deviation of resistance	$T_{C}=100^{\circ}C, R_{100}=493\Omega$	-5	-	5	%
P ₂₅	Power dissipation	$T_{\rm C}=25^{\circ}{\rm C}$	-	-	20	mW
B _{25/50}	B-constant	$R_2 = R_{25} exp[B_{25/50}(1/T_2 - 1/(298.15K))]$	-	3375	-	
B _{25/80}	B-constant	$R_2 = R_{25} exp[B_{25/80}(1/T_2 - 1/(298.15K))]$	-	3411	-	K
B _{25/100}	B-constant	$R_2 = R_{25} exp[B_{25/100}(1/T_2 - 1/(298.15K))]$	-	3433	-	

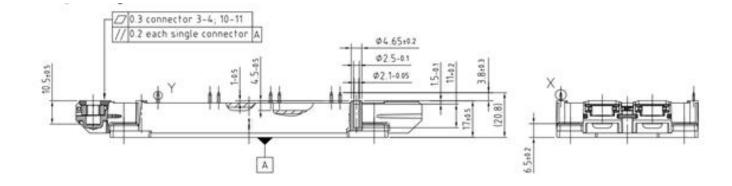
Module

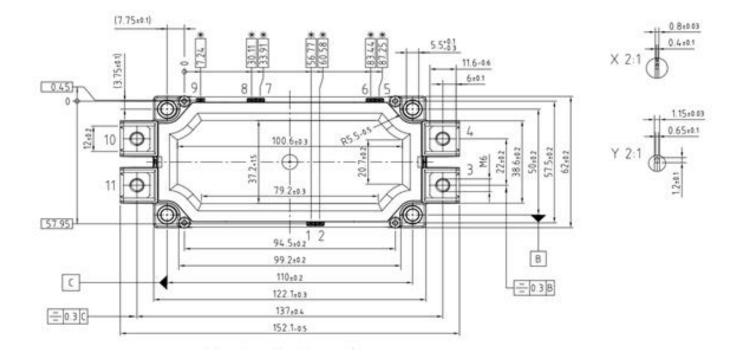
Symbol	Item	Conditions	Rating		5	Unit
VISOL	Isolation voltage	Terminals to baseplate, RMS,f=50Hz,t=1min	2500			V
-	Material of module baseplate	-	Cu		-	
-	Internal isolation	Basic insulation(class 1, IEC 61140)	Al ₂ O ₃			-
T _{stg}	Storage temperature	-	-40~125		5	°C
Symbol	Item	Candidiana	Values			Unit
		Conditions	Min.	Тур.	Max.	
М	Mounting torque for module mounting	Screw M6	3.0	-	5.0	Nm
	Terminal connection torque	Screw M6	2.5	-	5.0	Nm
ds	Creepage distance	Terminal to terminal	-	13	-	
		Terminal to base plate	-	14.5	-	mm
da	Clearance	Terminal to terminal	-	10	-	
		Terminal to base plate	-	12.5	-	mm
m	Weight	-	-	340	-	g

Circuit diagram headline









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